

METHODS AND ARTICLES INCLUDING A SHEET AND A CARRIER

CROSS-REFERENCE TO RELATED APPLICATIONS

[0001] This application claims the benefit of priority under 35 U.S.C. § 119 of U.S. Provisional Application Serial No. 62/185095 filed on June 26, 2015, the content of which is relied upon and incorporated herein by reference in its entirety.

TECHNICAL FIELD

[0002] The disclosure relates generally to methods and articles including a sheet and a carrier and, more particularly, to methods and articles providing a sheet that is temporarily bonded to a carrier.

BACKGROUND

[0003] There is a desire to provide flexible glass sheets that provide the potential to fabricate thinner, lighter, more flexible and more durable display configurations. However, the increased flexibility of the glass sheets provides an obstacle in processing the glass sheets with equipment typically designed to process relatively thick and relatively rigid glass sheets. To address the concern, the flexible glass sheet may be temporarily bonded to a carrier. The resulting article is relatively thicker and relatively more rigid compared to the flexible glass sheet itself. The article may then be handled by the equipment that processes the glass sheet while the glass sheet remains bonded to the carrier. After processing, the flexible glass sheet may be removed from the carrier for subsequent use in displays or other devices.

[0004] There is a desire to temporarily bond a flexible sheet (e.g. a flexible glass sheet) to a carrier by use of van der Waals bonding that is sufficient to retain bonding of the sheet to the carrier while the article is handled by the processing equipment. Still further, there is a desire to temporarily bond the flexible sheet to the carrier in such a manner as to inhibit, for example prevent or reduce, covalent bond formation between the sheet and the carrier that can complicate or prevent subsequent removal of the sheet from the carrier without damaging or destroying the sheet and/or the carrier. Increasing the surface roughness of one of a carrier bonding surface and a sheet bonding surface may inhibit, for example prevent or reduce, covalent bond formation between the sheet and the carrier during or following high temperature processing. However the increased surface roughness can significantly reduce the van der Waals bonding forces used during low temperature processing to bond the sheet and the carrier together to the point that spontaneous bonding of

the surfaces does not occur, or any bonding of the surfaces that does occur may be so weak that the bond cannot survive processing with the equipment.

SUMMARY

[0005] The following presents a simplified summary of the disclosure in order to provide a basic understanding of some example aspects described in the detailed description. The present disclosure provides a surface modification layer including a plasma polymerized material. The plasma polymerized material planarizes at least one of the carrier bonding surface and the sheet bonding surface having an otherwise moderate surface roughness (surface roughness as described herein refers to root mean square surface roughness, Rq). By reducing the surface roughness with the plasma polymerized material, van der Waals bonding forces may be high enough to permit an initial bond of the sheet to the carrier that will survive processing with the equipment. At the same time, the plasma polymerized material inhibits, for example prevents or reduces, covalent bond formation between the sheet and the carrier that would otherwise prevent separation of the sheet from the carrier following processing.

[0006] In the disclosure, there is provided an article includes a carrier including a carrier bonding surface, a sheet including a sheet bonding surface, and a surface modification layer disposed on at least one of the carrier bonding surface and the sheet bonding surface. The surface modification layer includes a plasma polymerized material. The plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface. The carrier bonding surface and the sheet bonding surface are bonded with the surface modification layer so that the carrier is temporarily bonded with the sheet.

[0006a] In an aspect, there is provided an article comprising:

a carrier comprising a carrier bonding surface;

a sheet comprising a sheet bonding surface; and

a surface modification layer disposed on at least one of the carrier bonding surface and the sheet bonding surface, wherein the surface modification layer comprises a plasma polymerized material, wherein the plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface, wherein the carrier bonding surface and the sheet bonding surface are bonded with the surface modification layer so that the carrier is temporarily bonded to the sheet, wherein the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness Rq within a range of 0.8 nm to 5.0 nm, and wherein the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness Rq less than 0.8 nm.

[0007] In one example, the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than about 0.8 nm.

[0008] In a further example, the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of about 0.8 nm to about 5.0 nm.

[0009] In another example, the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q greater than about 2.0 nm.

[0010] In yet another example, the surface modification layer has at least one of an elastic modulus and a plasticity so that at least one of a portion of the carrier bonding surface and a portion of the sheet bonding surface may penetrate into the surface

modification layer. For example, the elastic modulus is within a range of from about 0.6 GPa to about 20 GPa.

[0011] In still another example, at least one of the carrier and the sheet includes glass.

[0012] In still another example, the carrier has a thickness within a range of from about 200 microns to about 3 mm.

[0013] In still another example, the sheet has a thickness less than or equal to about 300 microns.

[0014] In still another example, the surface modification layer has a thickness within a range from about 0.1 nm to about 100 nm.

[0015] The first aspect may be provided alone or in combination with one or any combination of the examples discussed above.

[0016] In the disclosure, there is also provided an article includes a carrier including a carrier bonding surface, a sheet including a sheet bonding surface, and at least one of a carrier surface modification layer disposed on the carrier bonding surface and a sheet surface modification layer disposed on the sheet bonding surface. The at least one of the carrier surface modification layer and the sheet surface modification layer includes a plasma polymerized material. The plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface. The carrier bonding surface and the sheet bonding surface are bonded with at least one of the carrier surface modification layer and the sheet surface modification layer so that the carrier is temporarily bonded with the sheet.

[00016a] In another aspect, there is provided an article comprising:

a carrier comprising a carrier bonding surface;

a sheet comprising a sheet bonding surface; and

at least one of a carrier surface modification layer disposed on the carrier bonding surface and a sheet surface modification layer disposed on the sheet bonding surface, wherein the at least one of the carrier surface modification layer and the sheet surface modification layer comprises a plasma polymerized material, wherein the plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface, wherein the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of 0.8 nm to 5.0 nm, wherein the carrier bonding surface and the sheet bonding surface are bonded with the at least one of the carrier surface modification layer and the sheet surface modification layer so that the carrier is temporarily bonded with the sheet, and wherein the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than 0.8 nm.

[0017] In one example, with respect to the at least one of the carrier surface modification layer and the sheet surface modification layer, the article includes only the carrier surface modification layer. At least a portion of the sheet bonding surface penetrates into the carrier surface modification layer.

[0018] In another example, with respect to the at least one of the carrier surface modification layer and the sheet surface modification layer, the article includes only the sheet surface modification layer. At least a portion of the carrier bonding surface penetrates into the sheet surface modification layer.

[0019] In yet another example, with respect to the at least one of the carrier surface modification layer and the sheet surface modification layer, the article includes both the carrier surface modification layer and the sheet surface modification layer. At least one of (i) a portion of the sheet bonding surface penetrates into the carrier surface

modification layer and (ii) a portion of the carrier bonding surface penetrates into the sheet surface modification layer.

[0020] In still another example, the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than about 0.8 nm.

[0021] In still another example, the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of about 0.8 nm to about 5.0 nm.

[0022] The second aspect may be provided alone or in combination with one or any combination of the examples discussed above.

[0023] In the disclosure, there is also provided a method of making an article includes depositing a surface modification layer on at least one of a carrier bonding surface of a carrier and a sheet bonding surface of a sheet. The surface modification layer includes a plasma polymerized material. The plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface. The method includes bonding at least one of the carrier bonding surface and the sheet bonding surface with the surface modification layer so that the carrier is temporarily bonded with the sheet.

[0023a] In another aspect, there is provided a method of making an article comprising:

depositing a surface modification layer on at least one of a carrier bonding surface of a carrier and a sheet bonding surface of a sheet, wherein the surface modification layer comprises a plasma polymerized material, and wherein the depositing of the plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface; and

bonding the carrier bonding surface and the sheet bonding surface with the surface modification layer so that the carrier is temporarily bonded with the sheet, wherein the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of 0.8 nm to 5.0 nm, and wherein the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than 0.8 nm.

[0024] In one example, the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than about 0.8 nm.

[0025] In another example, the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of about 0.8 nm to about 5.0 nm.

[0026] In yet another example, the method further includes at least one of an elastic modulus and a plasticity of the surface modification layer that allow penetration of at least one of a portion of the carrier bonding surface and a portion of the sheet bonding surface into the surface modification layer.

[0027] The third aspect may be provided alone or in combination with one or any combination of the examples discussed above.

BRIEF DESCRIPTION OF THE DRAWINGS

[0028] The above and other features, aspects and advantages of the present invention are better understood when the following detailed description of the invention is read with reference to the accompanying drawings, in which:

[0029] **FIG. 1** illustrates an example article in an unassembled (e.g. unbonded) state;

[0030] **FIG. 2** illustrates an example article in an assembled (e.g. temporarily bonded) state; and

[0031] **FIGS. 3-14** illustrate various embodiments by which at least one of a carrier bonding surface and a sheet bonding surface is bonded with a surface modification layer so that a carrier is temporarily bonded with a sheet.

DETAILED DESCRIPTION

[0032] Examples will now be described more fully hereinafter with reference to the accompanying drawings. Whenever possible, the same reference numerals are used throughout the drawings to refer to the same or like parts. .

[0033] Referring to **FIG. 1** and **FIG. 2**, an example article **100** is provided with various example features that may be used either alone or in combination. The example article **100** is illustrated in **FIG. 1** in an unassembled (e.g. unbonded) state, while the example article **100** is illustrated in **FIG. 2** in an assembled (e.g. bonded state). As shown, the article **100** can include a carrier **110**, a sheet **120**, and a surface modification layer **130**. The carrier can include a carrier bonding surface **115**. The sheet can include a sheet bonding surface **125**. As shown in **FIG. 2**, the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** can be bonded together to form the article **100**, so that the carrier **110** is temporarily bonded with the sheet **120**.

[0034] The carrier **110** can be made of or include glass (e.g. alumino-silicate, boro-silicate, alumino-boro-silicate, soda-lime-silicate, and alkali containing or alkali-free), ceramic, glass-ceramic, metal, silicon, polysilicon, single crystal silicon, sapphire, quartz or any other material including those not explicitly listed herein either alone or in combination with other materials. Additionally, the carrier **110** may include one layer, as shown, or multiple layers (including multiple layers of the same or a different material) that are bonded together. Further, the carrier **110** may be of a Gen 1 size or larger, for example, Gen 2, Gen 3, Gen 4, Gen 5, Gen 8 or larger (e.g. sheet sizes from 100 mm x 100 mm to 3 meters x 3 meters or greater). The sheet **120** can be made of or include glass (e.g. alumino-silicate, boro-silicate, alumino-boro-silicate, soda-lime-silicate, and alkali containing or alkali-free), ceramic, glass-ceramic, metal, a polymer or polymers, a composite of a polymer or polymers and glass, silicon, polysilicon, single crystal silicon, sapphire, quartz, or any other material including those not explicitly listed herein either alone or in combination with other materials. Further, the sheet **120** may be of a Gen 1 size or larger, for example, Gen 2, Gen 3, Gen 4, Gen 5, Gen 8, or larger (e.g. sheet sizes from 100 mm x 100 mm to 3 meters x 3

meters or greater). Still further, the sheet **120** can be an interposer (e.g. an interposer sheet or an interposer wafer) comprising through hole vias.

[0035] The article **100** can have an article thickness **101**, the carrier **110** can have a carrier thickness **111**, the sheet **120** can have a sheet thickness **121**, and the surface modification layer **130** can have a surface modification layer thickness **131**. The article thickness **101** includes the carrier thickness **111**, the sheet thickness **121**, and the surface modification layer thickness **131**. In one example, the article **100** has an article thickness **101** within a range from about 0.4 mm to about 3.0 mm, including but not limited to greater than or equal to 0.4 mm, 0.5 mm, 0.6 mm, 0.7 mm, 0.8 mm, 0.9 mm, 1.0 mm, 2.0 mm, or 3.0 mm. It is to be understood that the article **100** can have an article thickness **101** that can be any thickness, including any thickness not explicitly disclosed herein (e.g. a thickness less than 0.4 mm, a thickness greater than 3.0 mm, or any other thickness). In another example, the carrier **110** can have a carrier thickness **111** within a range from about 0.2 mm to about 3 mm, including but not limited to 0.2 mm, 0.3 mm, 0.4 mm, 0.5 mm, 0.6 mm, 0.65 mm, 0.7 mm, 1.0 mm, 2.0 mm, or 3.0 mm. It is to be understood that the carrier can have a carrier thickness **111** that can be any thickness, including any thickness not explicitly disclosed herein (e.g. a thickness less than 0.2 mm, a thickness greater than 3 mm, or any other thickness). In yet another example, the sheet **120** can have a sheet thickness **121** less than or equal to about 300 microns, including but not limited 10-50 microns, 50-100 microns, 100-150 microns, 150-300 microns, or less than or substantially equal to 300, 250, 200, 190, 180, 170, 160, 150, 140, 130, 120, 110, 100, 90, 80, 70, 60, 50, 40, 30, 20, or 10 microns. It is to be understood that the sheet **120** can have a sheet thickness **121** that can be any thickness, including any thickness not explicitly disclosed herein (e.g. a thickness greater than 300 microns, or any other thickness). In still another example, the surface modification layer **130** can have a surface modification layer thickness **131** within a range from about 0.1 nm to about 100 nm. It is to be understood that the surface modification layer **130** can have a surface modification layer thickness **131** that can be any thickness, including any thickness not explicitly disclosed herein (e.g. a thickness less than 0.1 nm, a thickness greater than 100 nm, or any other thickness).

[0036] In some examples, the article thickness **101** can be configured to provide an article **100** having an article thickness **101** that can be processed in processing equipment, including existing processing equipment. For example, the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** can be bonded together and then undergo various processing. Following the processing, the sheet **120** and the carrier

110, including any devices that may be fabricated on the sheet during the processing, can be separated and the carrier **110** can be reused, for example. Some types of processing include vacuum processing, wet processing, ultrasonic cleaning processing, spin-rinse-dry (SRD) processing, and high temperature processing for example, FPD processing, p-Si and oxide TFT fabrication, IGZO backplane processing, and LTPS, amorphous silicon (aSi) bottom gate TFT, polycrystalline silicon (pSi) top gate TFT, amorphous oxide (IGZO) bottom gate TFT, touch screen fabrication, and interposer fabrication.

[0037] The surface modification layer **130** is configured to control a strength of the bond (e.g. energy of adhesion or bond energy) between the carrier bonding surface **115** and the sheet bonding surface **125**. In particular, the surface modification layer **130** is bonded with the carrier bonding surface **115** and the sheet bonding surface **125** in a manner sufficient to keep the sheet **120** and the carrier **110** bonded together during processing of the article **100**, while allowing the sheet **120** and the carrier **110** to be separated without damage (e.g. catastrophic damage, for example breaking of either of the carrier **110** or the sheet **120** into two or more pieces) following processing, i.e., so that the sheet **120** is temporarily bonded with the carrier **110**. The surface modification layer **130** can include a plasma polymerized material, formed by plasma deposition for example. As will be discussed more fully below, the plasma polymerized material can planarize the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**.

[0038] In general, the energy of adhesion (W) between two surfaces, as originally defined by Dupre (1869), is given by:

$$W = Y_1 + Y_2 - Y_{12} \quad (1)$$

(“A theory for the estimation of surface and interfacial energies. I. derivation and application to interfacial tension,” L. A. Girifalco and R. J. Good, J. Phys. Chem., V 61, p 904) where, (Y_1), (Y_2), and (Y_{12}) , Y_1 , Y_2 and Y_{12} are the surface energies of surface 1, surface 2, and the interfacial energy of surface 1 and surface 2, respectively. The individual surface energies (Y) are usually a combination of two terms: a dispersion component (Y^d), and a polar component (Y^p), where

$$Y = Y^d + Y^p \quad (2)$$

[0039] When the adhesion is mostly due to London dispersion forces (Y^d) and polar forces (Y^p), for example hydrogen bonding, the interfacial energy (Y_{12}) can be given by:

$$Y_{12} = Y_1 + Y_2 - 2\sqrt{Y_1^d Y_2^d} - 2\sqrt{Y_1^p Y_2^p} \quad (3)$$

(Girifalco and R. J. Good, as mentioned above).

[0040] After substituting (3) in (1), the energy of adhesion (W) can be approximated as:

$$W \sim 2 \left[\sqrt{Y_1^d Y_2^d} + \sqrt{Y_1^p Y_2^p} \right] \quad (4)$$

[0041] In the above equation (4), only van der Waals (and/or hydrogen bonding) components of adhesion energies are considered. These include polar-polar interaction (Keesom), polar-non polar interaction (Debye) and nonpolar-nonpolar interaction (London). However, other attractive energies may also be present, for example, covalent bonding and electrostatic bonding. Thus, in a more generalized form, the above equation (4) can be written as:

$$W \sim 2 \left[\sqrt{Y_1^d Y_2^d} + \sqrt{Y_1^p Y_2^p} \right] + W_c + W_e \quad (5)$$

where (W_c) and (W_e) are the covalent and electrostatic adhesion energies.

[0042] Bond energy is the energy required to separate a sheet from a carrier. The bond energy may be measured in various different manners. For example, as used herein, the bond energy can be measured as follows.

[0043] Bond energy can be measured using the double cantilever beam method (also known as the wedge method). In this method, a wedge of known thickness (t) is placed between the bonded sheet and the carrier at an edge. The wedge creates a characteristic delamination distance (L). This delamination distance is measured and used to calculate the bond energy (Y_{BE}).

$$Y_{BE} = \frac{3t^2 E_1 t_1^3 E_2 t_2^3}{16L^4 (E_1 t_1^3 + E_2 t_2^3)} \quad (6)$$

where (E_1) is the Elastic modulus of the carrier, (t_1) is the thickness of the carrier, (E_2) is the Elastic modulus of the sheet, and (t_2) is the thickness of the sheet.

[0044] Covalent adhesion energy, for example as in silicon wafer bonding, includes a situation where an initially hydrogen bonded pair of wafers are heated to a higher temperature to convert much or all the silanol-silanol hydrogen bonds to Si-O-Si covalent bonds. The initial, room temperature, hydrogen (or van der Waals) bonding produces an adhesion energy of approximately 100-200 mJ/m² which is sufficient to hold the wafers together during certain processing while still permitting separation of the bonded surfaces. However, during high temperature processing (e.g. processing including temperatures within a range from about 400 to about 800 °C), a fully covalently bonded wafer pair is formed and the bonded surfaces cannot be separated. The bond created during the high temperature processing has

an adhesion energy of approximately 1000-3000 mJ/m² and the two wafers act as a monolith (e.g. the sheet bonding surface **125** is permanently bonded to the carrier bonding surface **115**).

[0045] In another example, if both surfaces to be bonded are perfectly coated with a low surface energy material (e.g. a hydrocarbon polymer or a fluoropolymer) having a thickness large enough to shield the effect of the underlying substrate, the adhesion energy is that of the low surface energy coating material. This bond can be very low leading to low or no adhesion between the bonding surfaces such that the bonded article cannot undergo processing without, for example, the sheet **120** separating from the carrier **110**.

[0046] Consider two cases: (a) two standard clean 1 (e.g. SC1, as is known in the art) cleaned glass surfaces saturated with silanol groups bonded together at room temperature via hydrogen bonding (whereby the adhesion energy is approximately 100-200 mJ/m²) followed by heating to a high temperature which converts the silanol groups to covalent Si-O-Si bonds (whereby the adhesion energy becomes approximately 1000-3000 mJ/m²); and (b) two glass surfaces perfectly coated with a coating with low surface adhesion energy (e.g. about 12 mJ/m² per surface) bonded at room temperature and heated to a high temperature. In case (a), the adhesion energy after heating to a high temperature is too strong for the pair of glass surfaces to be detachable. In the case (b), not only do the surfaces not bond at room temperature (because the total adhesion energy of about 24 mJ/m², when the surfaces are put together, is too low), but they also do not bond at high temperature as there are no (or too few) polar reacting groups. Accordingly, between these two extremes, a range of adhesion energies exists, for example between about 50-1000 mJ/m², which can produce the desired degree of controlled, or temporary, bonding.

[0047] The present application discloses methods and apparatus for providing an article **100** including a surface modification layer **130** configured to temporarily bond the carrier bonding surface **115** and the sheet bonding surface **125**, for example, during processing, while also permitting separation of the carrier **110** and the sheet **120** following processing. Equation (5) describes that the adhesion energy is a function of four surface energy parameters plus the covalent and electrostatic energy, if any. Therefore, an appropriate adhesion energy can be achieved by controlling surface modifiers (e.g. the surface modification layer **130**). In one example, at least one of the carrier **110** and the sheet **120** includes glass.

[0048] Furthermore, the present application discloses unexpected results. In particular, it was expected that depositing a coating or layer (e.g. surface modification layer

130) on at least one of the carrier bonding surface **115** and the sheet bonding surface **125** would have no effect (e.g. remain the same) or emphasize (e.g. increase) a surface roughness (e.g. a surface roughness R_q) of the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**. However, the present application discloses a surface modification layer **130** disposed on at least one of the carrier bonding surface **115** and the sheet bonding surface **125**, wherein the surface modification layer **130** comprises a plasma polymerized material, and wherein—unexpectedly—the plasma polymerized material planarizes (e.g. reduces a surface roughness of) the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**.

[0049] Based on the surprising and unexpected planarization associated with the plasma polymerized material, the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** are bonded together such that the article **100** can undergo processing and, following processing, the carrier **110** and the sheet **120** can be separated from each other, i.e., the carrier **110** is temporarily bonded with the sheet **120**. It is to be understood, with respect to the surface modification layer **130** “planarizing” the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**, that the surface modification layer **130** is to be understood as disposed on the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**. That is, the surface modification layer forms a layer or coating on the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**, and, once disposed on these surfaces, the layer or coating has a surface roughness (e.g. a surface roughness R_q) that either alone or in combination with the surface roughness (e.g. surface roughness R_q) of the underlying at least one of the carrier bonding surface **115** and the sheet bonding surface **125** is less than the surface roughness (e.g. surface roughness R_q) of the underlying at least one of the carrier bonding surface **115** and the sheet bonding surface **125**.

[0050] For example, the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface can have a surface roughness R_q less than about 0.8 nm. In another example, the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**, without planarization, can have a surface roughness R_q within a range of about 0.8 nm to about 5.0 nm. In yet another example, the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**, without planarization, can have a surface roughness R_q greater than about 2.0 nm. In still another example, the surface modification layer **130** has an elastic modulus and a plasticity. At least one of the elastic modulus and the plasticity can be such that at least a portion of at least one of the carrier bonding surface **115**

and the sheet bonding surface **125** may penetrate into the surface modification layer **130**. For example, the elastic modulus can be within a range of from about 0.6 GPa to about 20 GPa. It is to be understood that the surface modification layer **130** can have at least one of an elastic modulus and a plasticity such that at least a portion of at least one of the carrier bonding surface **115** and the sheet bonding surface **125** may penetrate into the surface modification layer **130**, including any elastic modulus or plasticity not explicitly disclosed herein (e.g. an elastic modulus less than 0.6 GPa, an elastic modulus greater than 20 GPa, or any other elastic modulus or plasticity).

[0051] An example method of making an article includes depositing a surface modification layer **130** on at least one of a carrier bonding surface **115** of a carrier **110** and a sheet bonding surface **125** of a sheet **120**. The surface modification layer **130** comprises a plasma polymerized material. The plasma polymerized material planarizes the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**. The method further includes bonding at least one of the carrier bonding surface **115** and the sheet bonding surface **125** with the surface modification layer **130**. In one example, the method further includes choosing at least one of an elastic modulus and a plasticity of the surface modification layer **130** to allow penetration of at least a portion of at least one of the carrier bonding surface **115** and the sheet bonding surface **125** into the surface modification layer **130**.

[0052] FIGS. 3-14 illustrate various different embodiments by which the carrier bonding surface **115** and the sheet bonding surface **125** can be bonded with the surface modification layer **130** so that the carrier **110** is temporarily bonded with the sheet **120**. For illustrative purposes, the corresponding surface roughness (e.g. surface roughness R_q) of the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** is shown as a relative surface roughness. Further, the surface modification layer **130** can be disposed over the entirety of the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** (e.g. 100% coverage). In other examples, the surface modification layer **130** can be disposed over less than the entirety of the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** (e.g. less than 100% coverage).

[0053] Still further, it is to be understood that the surface roughness is illustrated as a jagged or triangular pattern merely for illustrative purposes and is not to be construed as limiting the scope of disclosure. Any shape, size, or distribution of asperities on any one or more of the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** are contemplated herein. Moreover, the at least one of the carrier

bonding surface **115** and the sheet bonding surface **125** can penetrate any amount into the surface modification layer **130**. It is to be understood that the more penetration of the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** into the surface modification layer **130**, the greater the corresponding surface area of the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** in contact with the surface modification layer **130**, and the greater the bond strength (e.g. energy of adhesion) between the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** and the surface modification layer **130**. The amount of penetration can be controlled, for example, by at least one of adjusting at least one of the elastic modulus and the plasticity of the surface modification layer **130**, and applying varying amounts of pressure (e.g. by lamination, or in an autoclave) on at least one of the carrier **110** and the sheet **120**, and varying the thickness of the surface modification layer **130** such that the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** penetrates a greater amount or a lesser amount into the surface modification layer **130**.

[0054] As shown in **FIG. 3**, the carrier bonding surface **115** and the sheet bonding surface **125** can have the same or similar surface roughness (e.g. surface roughness R_q), depicted as relatively smooth (e.g. less than 0.8 nm), and the carrier bonding surface **115** and the sheet bonding surface **125** can be bonded with the surface modification layer **130** so that the carrier **110** is temporarily bonded with the sheet **120**. As shown in **FIG. 4**, the carrier bonding surface **115** can have a surface roughness (e.g. surface roughness R_q), depicted as relatively smooth (e.g. less than 0.8 nm) and the sheet bonding surface **125** can have a surface roughness (e.g. surface roughness R_q), depicted as moderately rough (e.g. within a range from about 0.8 nm to about 5.0 nm). As shown, the surface modification layer **130** planarizes the moderately rough sheet bonding surface **125**, such that the carrier bonding surface **115** and the sheet bonding surface **125** can be bonded with the surface modification layer **130** so that the carrier **110** is temporarily bonded with the sheet **120**. As shown in **FIG. 5**, the carrier bonding surface **115** can have a surface roughness (e.g. surface roughness R_q), depicted as moderately rough (e.g. within a range from about 0.8 nm to about 5.0 nm) and the sheet bonding surface **125** can have a surface roughness (e.g. surface roughness R_q), depicted as relatively smooth (e.g. less than 0.8 nm). As shown, the surface modification layer **130** planarizes the moderately rough carrier bonding surface **115**, such that the carrier bonding surface **115** and the sheet bonding surface **125** can be bonded with the surface modification layer **130** so that the carrier **110** is temporarily bonded with the sheet **120**. As shown in **FIG. 6**, the carrier bonding surface **115** and the sheet bonding surface **125** can have the same or

similar surface roughness (e.g. surface roughness R_q), depicted as moderately rough (e.g. within a range from about 0.8 nm to about 5.0 nm). As shown, the surface modification layer **130** can planarize the moderately rough carrier bonding surface **115** and the moderately rough sheet bonding surface **125**, such that the carrier bonding surface **115** and the sheet bonding surface **125** can be bonded with the surface modification layer **130** so that the carrier **110** is temporarily bonded with the sheet **120**. In other examples, the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** can have any surface roughness (e.g. a surface roughness R_q greater than 5.0 nm), including a surface roughness R_q not explicitly disclosed herein, and the surface modification layer **130** can planarize the carrier bonding surface **115** and the sheet bonding surface **125**, such that the carrier bonding surface **115** and the sheet bonding surface **125** can be bonded with the surface modification layer **130** so that the carrier **110** is temporarily bonded with the sheet **120**.

[0055] As shown in FIGS. 3-6, the carrier bonding surface **115** and the sheet bonding surface **125** can be spaced apart from each other (e.g. not touching) with the surface modification layer **130** therebetween. In such a configuration, little to no covalent bonding between the carrier bonding surface **115** and the sheet bonding surface **125** is observed, even following processing at high temperatures. Rather, in such a configuration, the predominant force bonding the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** together is the van der Waals forces between the carrier bonding surface **115** and the surface modification layer **130** and the van der Waals forces between the sheet bonding surface **125** and the surface modification layer **130**. Covalent bonding between the sheet bonding surface **125** and the surface modification layer **130** as well as covalent bonding between the carrier bonding surface **115** and the surface modification layer **130** may also occur as long as such covalent bonding has minimal or no impact on the ability to separate the carrier **110** and the sheet **120** from each other following processing. For example, the carrier **110** and the sheet **120** can be separated from each other by at least one of adhesive failure (e.g. where the surface modification layer **130** separates from at least one of the carrier bonding surface **115** and the sheet bonding surface **125**) and cohesive failure (e.g. where the surface modification layer **130** separates from itself).

[0056] As shown in FIGS. 7-9, the carrier bonding surface **115** and the sheet bonding surface **125** can be spaced apart from each other (e.g. not touching) with the surface modification layer **130** therebetween in some locations, and contacting each other, without the surface modification layer **130** therebetween, in other locations. In such a configuration, little to no covalent bonding between the carrier bonding surface **115** and the sheet bonding

surface **125** is observed in the regions where the carrier bonding surface **115** and the sheet bonding surface **125** are spaced apart from each other (e.g. not touching) with the surface modification layer **130** therebetween, even following processing at high temperatures. Covalent bonding may be observed between the carrier bonding surface **115** and the sheet bonding surface **125** in regions where the carrier bonding surface **115** and the sheet bonding surface **125** are contacting each other, without the surface modification layer **130** therebetween. In such a configuration, the predominant force bonding the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** together is still the van der Waals forces between the carrier bonding surface **115** and the surface modification layer **130** and the van der Waals forces between the sheet bonding surface **125** and the surface modification layer **130**. As with the example embodiments illustrated in **FIGS. 3-6**, described above, covalent bonding between the sheet bonding surface **125** and the surface modification layer **130** as well as covalent bonding between the carrier bonding surface **115** and the surface modification layer **130** of the example embodiments illustrated in **FIGS. 7-9** may also occur so long as such covalent bonding has minimal or no impact on the ability to separate the carrier **110** and the sheet **120** from each other following processing. For example, the carrier **110** and the sheet **120** can be separated from each other by at least one of adhesive failure (e.g. where the surface modification layer **130** separates from at least one of the carrier bonding surface **115** and the sheet bonding surface **125**) and cohesive failure (e.g. where the surface modification layer **130** separates from itself). Moreover, because the predominant force bonding the carrier **110** and the sheet **120** is the van der Waals force between the surface modification layer **130** and at least one of the carrier bonding surface **115** and the sheet bonding surface **125**, any covalent bonds formed between the carrier bonding surface **115** and the sheet bonding surface **125** (e.g. in regions where the carrier bonding surface **115** and the sheet bonding surface **125** are contacting) can be broken (e.g. following processing) without damaging (e.g. breaking into two or more pieces) either or both of the carrier **110** and the sheet **120** to allow separation of the carrier **110** and the sheet **120**.

[0057] As shown in **FIG. 7**, the carrier bonding surface **115** can have a surface roughness (e.g. surface roughness R_q), depicted as relatively smooth (e.g. less than 0.8 nm) and the sheet bonding surface **125** can have a surface roughness (e.g. surface roughness R_q), depicted as moderately rough (e.g. within a range from about 0.8 nm to about 5.0 nm) with the moderately rough sheet bonding surface **125** contacting the relatively smooth carrier bonding surface **115** in some locations, without the surface modification layer **130**

therebetween, and the moderately rough sheet bonding surface **125** being spaced apart from the relatively smooth carrier bonding surface **115**, with the surface modification layer **130** therebetween, in other locations. As shown, the surface modification layer **130** planarizes the moderately rough sheet bonding surface **125**, such that the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** can be bonded together to form a temporary bond between the carrier **110** and the sheet **120**.

[0058] As shown in **FIG. 8**, the carrier bonding surface **115** can have a surface roughness (e.g. surface roughness R_q), depicted as moderately rough (e.g. within a range from about 0.8 nm to about 5.0 nm) and the sheet bonding surface **125** can have a surface roughness (e.g. surface roughness R_q), depicted as relatively smooth (e.g. less than 0.8 nm), with the moderately rough carrier bonding surface **115** contacting the relatively smooth sheet bonding surface **125** in some locations, without the surface modification layer **130** therebetween, and the moderately rough carrier bonding surface **115** being spaced apart from the relatively smooth sheet bonding surface **125**, with the surface modification layer **130** therebetween, in other locations. As shown, the surface modification layer **130** planarizes the moderately rough carrier bonding surface **115**, such that the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** can be bonded together to form a temporary bond between the carrier **110** and the sheet **120**.

[0059] As shown in **FIG. 9**, the carrier bonding surface **115** and the sheet bonding surface **125** can have the same or similar surface roughness (e.g. surface roughness R_q), depicted as moderately rough (e.g. within a range from about 0.8 nm to about 5.0 nm) with the moderately rough sheet bonding surface **125** contacting the moderately rough carrier bonding surface **115** in some locations, without the surface modification layer **130** therebetween, and the moderately rough sheet bonding surface **125** being spaced apart from the moderately rough carrier bonding surface **115**, with the surface modification layer **130** therebetween, in other locations. As shown, the surface modification layer **130** can planarize the moderately rough carrier bonding surface **115** and the moderately rough sheet bonding surface **125**, such that the carrier bonding surface **115**, the sheet bonding surface **125**, and the surface modification layer **130** can be bonded together to form a temporary bond between the carrier **110** and the sheet **120**.

[0060] **FIGS. 10-14** show the carrier **110** including the carrier bonding surface **115**, the sheet **120** including the sheet bonding surface **125**, and at least one of a carrier surface modification layer **130a** disposed on the carrier bonding surface **115** and a sheet surface modification layer **130b** disposed on the sheet bonding surface **125**. The at least one of the

carrier surface modification layer **130a** and the sheet surface modification layer **130b** comprises a plasma polymerized material. The plasma polymerized material planarizes the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**. The carrier bonding surface **115**, the sheet bonding surface **125**, and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** are bonded together to form a temporary bond between the carrier **110** and the sheet **120**.

[0061] With respect to the example embodiments illustrated in **FIGS. 10-14**, little to no covalent bonding between the carrier bonding surface **115** and the sheet bonding surface **125** is observed, even following processing at high temperatures. Rather, in such a configuration, the predominant force bonding the carrier bonding surface **115**, the sheet bonding surface **125**, and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** together is (i) the van der Waals forces between the carrier bonding surface **115** and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**; (ii) the van der Waals forces between the sheet bonding surface **125** and the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**; and (iii) to the extent surface modification layers **130a** and **130b** are both present, the van der Waals forces between the carrier surface modification layer **130a** and the sheet surface modification layer **130b**. In addition, little to no covalent bonding between the carrier bonding surface **115** and the sheet bonding surface **125** is observed in the regions where the carrier bonding surface **115** and the sheet bonding surface **125** are spaced apart from each other (e.g. not touching) with the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** therebetween, even following processing at high temperatures. Covalent bonding may be observed between the carrier bonding surface **115** and the sheet bonding surface **125** in regions where the carrier bonding surface **115** and the sheet bonding surface **125** are contacting each other, without the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** therebetween. In such a configuration, the predominant force bonding the carrier bonding surface **115**, the sheet bonding surface **125**, and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** together is still: (i) the van der Waals forces between the carrier bonding surface **115** and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**; (ii) the van der Waals forces between the sheet bonding surface **125** and the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**; and (iii) to the extent surface modification layers

130a and **130b** are both present, the van der Waals forces between the carrier surface modification layer **130a** and the sheet surface modification layer **130b**. As with the example embodiments illustrated in **FIGS. 3-9**, described above, covalent bonding between the carrier bonding surface **115** and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** as well as covalent bonding between the sheet bonding surface **125** and the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**, as well as covalent bonding between the surface modification layers **130a** and **130b** when both are present, of the example embodiments illustrated in **FIGS. 10-14** may also occur so long as such covalent bonding has minimal or no impact on the ability to separate the carrier **110** and the sheet **120** from each other following processing. For example, the carrier **110** and the sheet **120** can be separated from each other by at least one of adhesive failure (e.g. where the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** separates from at least one of the carrier bonding surface **115** and the sheet bonding surface **125**) and cohesive failure (e.g. where the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** separates from at least one of itself and each other). Moreover, because the predominant force bonding the carrier **110** and the sheet **120** is (i) the van der Waals forces between the carrier bonding surface **115** and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**; (ii) the van der Waals forces between the sheet bonding surface **125** and the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**; and (iii) to the extent surface modification layers **130a** and **130b** are both present, the van der Waals forces between the carrier surface modification layer **130a** and the sheet surface modification layer **130b**, any covalent bonds formed between the carrier bonding surface **115** and the sheet bonding surface **125** (e.g. in regions where the carrier bonding surface **115** and the sheet bonding surface **125** are contacting) can be broken (e.g. following processing) without damaging (e.g. breaking into two or more pieces) either or both of the carrier **110** and the sheet **120** to allow separation of the carrier **110** and the sheet **120**.

[0062] **FIG. 10** shows, with respect to the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**, the article comprises both the carrier surface modification layer **130a** disposed on the carrier bonding surface **115** and the sheet surface modification layer **130b** disposed on the sheet bonding surface **125**. In one example, at least a portion of at least one of the sheet bonding surface **125** penetrates into the carrier surface modification layer **130a** and the carrier bonding surface **115** penetrates

into the sheet surface modification layer **130b**. In other examples, the sheet bonding surface **125** may not extend beyond the sheet surface modification layer **130b**, and the carrier bonding surface **115** may not extend beyond the carrier surface modification layer **130a**. In still other examples, at least a portion of the sheet bonding surface **125** may penetrate into the carrier surface modification layer **130a**, whereas the carrier bonding surface **115** may not extend beyond the carrier surface modification layer **130a**. And in still other examples, at least a portion of the carrier bonding surface **115** may penetrate into the sheet surface modification layer **130b**, whereas the sheet bonding surface **125** may not extend beyond the sheet surface modification layer **130b**.

[0063] **FIG. 11** shows, with respect to the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**, the article comprises only the sheet surface modification layer **130b** disposed on the sheet bonding surface **125**. As shown in **FIG. 13**, at least a portion of the carrier bonding surface **115** penetrates into the sheet surface modification layer **130b**. As shown the sheet surface modification layer **130b** planarizes the sheet bonding surface **125** such that the carrier bonding surface **115**, the sheet bonding surface **125**, and the sheet surface modification layer **130b** (with at least a portion of the carrier bonding surface **115** penetrating thereinto) are bonded together to form a temporary bond between the carrier **110** and the sheet **120**.

[0064] **FIG. 12** shows, with respect to the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**, the article comprises only the carrier surface modification layer **130a** disposed on the carrier bonding surface **115**. As shown in **FIG. 14**, at least a portion of the sheet bonding surface **125** penetrates into the carrier surface modification layer **130a**. As shown the carrier surface modification layer **130a** planarizes the carrier bonding surface **115** such that the carrier bonding surface **115**, the sheet bonding surface **125**, and the carrier surface modification layer **130a** (with at least a portion of the sheet bonding surface **125** penetrating thereinto) are bonded together to form a temporary bond between the carrier **110** and the sheet **120**.

[0065] As shown in **FIG. 13** and **FIG. 14**, gaps (e.g. air gaps or “blisters,” as is known in the art) can be formed between: (i) the carrier bonding surface **115** and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**; and/or (ii) the sheet bonding surface **125** and the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**. In other examples (e.g. **FIG. 10**) the amount of penetration of (i) the carrier bonding surface **115** into the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer

130b; and/or (ii) the sheet bonding surface **125** into the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**, can be controlled such that no blisters are formed between (i) the carrier bonding surface **115** and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**; and/or the sheet bonding surface **125** and the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**. For example, by at least one of adjusting at least one of the elastic modulus and the plasticity of the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**, and applying varying amounts of pressure (e.g. by lamination, or in an autoclave) on at least one of the carrier **110** and the sheet **120**, and varying the thickness of the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**, the at least one of the carrier bonding surface **115** and the sheet bonding surface **125** can penetrate a greater amount or a lesser amount into the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b**. In other examples, penetration of at least one of (i) the carrier bonding surface **115** into the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** and (ii) the sheet bonding surface **125** into the at least one of the sheet surface modification layer **130b** and the carrier surface modification layer **130a**, can provide an energy of adhesion (e.g. based on van der Waals bonding) that is less than, equal to, or greater than an energy of adhesion (e.g. based on at least one of van der Waals bonding and covalent bonding) between surfaces which, for example, have no surface modification layer (e.g. a compliant surface layer) therebetween, irrespective of the relative surface roughness of either or both of the surfaces.

[0066] It is to be understood that any one or more combinations of the embodiments illustrated in **FIGS. 3-14** can be combined to temporarily bond the carrier **110** and the sheet **120**. Further, in one example, the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface can have a surface roughness R_q less than about 0.8 nm. In other example, the at least one of the carrier bonding surface **115** and the sheet bonding surface **125**, prior to planarization, can have a surface roughness R_q within a range of about 0.8 nm to about 5.0 nm. As provided above, other surface roughnesses of the carrier bonding surface **115**, the sheet bonding surface **125**, and the at least one of the carrier surface modification layer **130a** and the sheet surface modification layer **130b** are contemplated herein.

[0067] As noted, the surface modification layer **130** can include a plasma polymerized material. In one example, the plasma polymerized material can include a

plasma polymer film formed by a chemical vapor deposition process in which precursors are activated and deposited by a plasma to form polymeric materials. In another example, the plasma polymerized material (e.g. the plasma polymer film) can include aliphatic or aromatic hydrocarbons, polyesters, or polyimides. In still other examples plasma polymers may be deposited under atmospheric or reduced pressure. Still further, plasma polymerized material can be formed by plasma deposition that includes plasma excitation (e.g. DC or RF parallel plate, Inductively Coupled Plasma (ICP), Electron Cyclotron Resonance (ECR), downstream microwave, or RF plasma) from source gases. In some examples, source gases can include fluorocarbon sources (e.g. CF₄, CHF₃, C₂F₆, C₃F₆, C₂F₂, CH₃F, C₄F₈, chlorofluoro carbons, or hydrochlorofluoro carbons); hydrocarbons (e.g. alkanes, including methane, ethane, propane, or butane); alkenes (including ethylene or propylene, for example); alkynes (including acetylene, for example); or aromatics (including benzene or toluene, for example). In other examples source gases can include hydrogen or other gas sources, including SF₆. In addition, plasma polymerization creates a layer of highly cross-linked material. In some examples, control of reaction conditions and source gases can be used to control the film thickness, density, and chemistry to, for example, tailor the functional groups to a desired application. It is to be understood that the specific plasma polymer films described herein are non-limiting representative examples, and one skilled in the art will recognize similar advantages may be achieved with different plasma geometry and source materials, including plasma polymers not explicitly disclosed herein. In particular, the present application contemplates any plasma polymerized material configured to planarize a surface as within the scope of disclosure.

[0068] Moreover, the following specific examples are in accordance with example embodiments described above and are to be understood as non-limiting representative examples.

[0069] In a first example, aliphatic plasma polymer films were deposited in an Oxford PlasmaLab 100 etch tool from methane and hydrogen. Process conditions were 2 standard cubic centimeters per minute (sccm) methane, 38 sccm hydrogen, 25 milli Torrs (mT) pressure 275 Watts (W) 13.56 Mega Hertz (MHz) Radio Frequency (RF). Process times were varied to adjust plasma polymer thickness from 11 to 60 nano meters (nm). Thickness was measured on an n&k analyzer using an amorphous carbon model. Surfaces were activated in the same Oxford tool with 25 sccm Nitrogen, 25 sccm Oxygen, O₂ 10 mT 300 W RF and a process time of 5 seconds (sec.). Further, 200 micrometer (um, or micron) thick glass substrates were etched in an aqueous solution 433 milli liters (ml) De-Ionized (DI)

water, 106 ml hydrochloric acid, and 11 ml 49% hydrofluoric acid at room temperature for 1 minute (min.). This produced a surface roughness of 1.0 nm Root Mean Square (RMS, Rq) as measured by Atomic Force Microscope (AFM). The roughened thin glass was bonded to the plasma polymer surface which was then bonded together with the carrier by applying the substrate to the carrier. Because of the high surface energy of the plasma polymer, surface bonding was self-propagating. A Teflon squeegee was used to remove any entrapped bubbles formed by particles and curvature in the bonding front. Bonded samples were annealed for 10 min at 300 °C in flowing nitrogen in an MPT rapid thermal processing system (RTP) on a silicon carbide susceptor. Bond energy was measured by the wedge test. As shown in Table 1 below, roughness (Rq) was observed to decrease with increasing plasma polymer thickness. The bond energy increases with increasing polymer thickness reaching a value near that expected for van der Waals interaction between the thin glass and treated plasma polymer coated carrier as surface roughness decreases below 0.8 nm RMS (Rq).

Thickness (nm)	Bond Energy (mJ/m²)	Rq (nm)
11.2	14.7	1.01
16.3	14.7	0.82
23.8	205.3	0.81
39.2	210.1	0.72
57.3	156.2	0.57

TABLE 1

[0070] In a second example, a set of thin glass interposers were formed from a 200 μ m thick glass substrate made of Corning® EAGLE XG ® glass by a process of laser damage to form vias, and etch in the HF-HNO₃ solution described above. Etching the vias reduced the thickness of the substrate to 180 μ m, produced 50 μ m diameter vias, and AFM showed the surface roughness after etching as 1 nm Rq. These interposer samples were coated with a plasma polymer of varying thickness as described with respect to the first example and were bonded to a 0.7 mm thick glass carrier made of Corning® EAGLE EXG® glass. Samples were annealed in an RTP system in N₂ at 300 °C for 10 min. Bond Energy (BE, in milli Joules per meter squared (mJ/m²)) versus plasma polymer thickness (in nm) is shown below in Table 2. For a plasma polymer thickness of greater than 40 nm, a suitable bond energy of greater than 200 mJ/m² can be achieved.

Polymer thickness (nm)	BE (mJ/m²)
11	48
17	79
30	128
39	240
57	250

TABLE 2

[0071] In a third example, a set of thin glass interposers was formed from a 200 μm thick glass substrate made of Corning® EAGLE XG® glass by a process of laser damage to form vias, and etch in the HF-HNO₃ solution described above. Etching the vias reduces the thickness of the substrate to 180 μm and produces 30 μm diameter vias. These interposer samples were coated with a plasma polymer of varying thickness in the Oxford tool as described in the first example except plasma polymer deposition conditions were 10 sccm ethylene 50 sccm hydrogen 5 mT pressure 1500 W RF applied to the coil 50 W RF bias followed by 5 sec treatment time at 35 sccm nitrogen 5 sccm oxygen 15 mT pressure 800 W RF applied to the coil 50 W RF bias. Interposers were bonded to a 0.7 mm thick glass carrier made of Corning® EAGLE EXG® glass. Samples were annealed in an RTP system in N₂ at 300 °C for 10 min. A bond energy of 312 mJ/m² was found for a polymer thickness of 13.7 nm.

[0072] It will be apparent to those skilled in the art that various modifications and variations can be made to the present disclosure without departing from the spirit and scope of the subject matter claimed.

CLAIMS

1. An article comprising:

- a carrier comprising a carrier bonding surface;
- a sheet comprising a sheet bonding surface; and
- a surface modification layer disposed on at least one of the carrier bonding surface and the sheet bonding surface, wherein the surface modification layer comprises a plasma polymerized material, wherein the plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface, wherein the carrier bonding surface and the sheet bonding surface are bonded with the surface modification layer so that the carrier is temporarily bonded to the sheet, wherein the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of 0.8 nm to 5.0 nm, and wherein the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than 0.8 nm.

2. An article comprising:

- a carrier comprising a carrier bonding surface;
- a sheet comprising a sheet bonding surface; and
- at least one of a carrier surface modification layer disposed on the carrier bonding surface and a sheet surface modification layer disposed on the sheet bonding surface, wherein the at least one of the carrier surface modification layer and the sheet surface modification layer comprises a plasma polymerized material, wherein the plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface, wherein the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of 0.8 nm to 5.0 nm, wherein the carrier bonding surface and the sheet bonding surface are bonded with the at least one of the carrier surface modification layer and the sheet surface modification layer so that the carrier is temporarily bonded with the sheet, and wherein the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than 0.8 nm.

3. The article of claim 1 or claim 2, wherein the surface modification layer has at least one of an elastic modulus and a plasticity configured to allow penetration of at least a portion of at least one of the carrier bonding surface and the sheet bonding surface into the surface modification layer.

4. The article of claim 3, wherein the elastic modulus is within a range of from 0.6 GPa to 20 GPa.

5. The article of any one of claims 1-4, wherein at least one of the carrier and the sheet comprises glass.

6. The article of any one of claims 1-5, wherein the carrier has a thickness within a range of from 200 microns to 3 mm.

7. The article of any one of claims 1-6, wherein the sheet has a thickness less than or equal to 300 microns.

8. A method of making an article comprising:

depositing a surface modification layer on at least one of a carrier bonding surface of a carrier and a sheet bonding surface of a sheet, wherein the surface modification layer comprises a plasma polymerized material, and wherein the depositing of the plasma polymerized material planarizes the at least one of the carrier bonding surface and the sheet bonding surface; and

bonding the carrier bonding surface and the sheet bonding surface with the surface modification layer so that the carrier is temporarily bonded with the sheet, wherein the at least one of the carrier bonding surface and the sheet bonding surface has a surface roughness R_q within a range of 0.8 nm to 5.0 nm, and wherein the at least one of the planarized carrier bonding surface and the planarized sheet bonding surface has a surface roughness R_q less than 0.8 nm.

9. The method of claim 8, wherein at least one of an elastic modulus and a plasticity of the surface modification layer allow penetration of at least a portion of at least one of the carrier bonding surface and the sheet bonding surface into the surface modification layer.